## FOR SMALL TYPE COLOUR TV CHROMA OUTPUT APPLICATION SILICON NPN TRIPLE DIFFUSED TYPE

#### **DESCRIPTION**

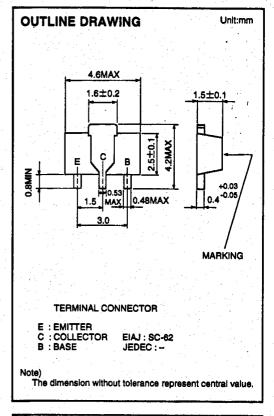
2SC5210 is a silicon NPN triple diffused transistor designed for colour TV chrom output circuit, high voltage switching circuit application.

#### **FEATURE**

- ●High voltage VcEo=250V
- ●Low Cob Cob=3.5pF typ
- ●High ft ft=80MHz typ
- Small package for mounting

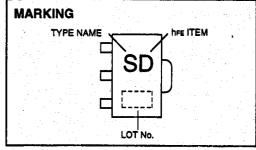
#### **APPLICATION**

Small type colour TV chroma output circuit, high voltage switching circuit.



## MAXIMUM RATINGS (Ta=25°C)

| Symbol | Parameter                      | Ratings     | Unit |
|--------|--------------------------------|-------------|------|
| Vcво   | Collector to Base voltage      | 300         | V    |
| VEBO   | Emitter to Base voltage        | 5           | V    |
| VCEO   | Collector to Emitter voltage   | 250         | V    |
| lc     | Collector current              | 100         | mA.  |
| Pc .   | Collector dissipation(Ta=25°C) | 500         | mW   |
| Tj     | Junction temperature           | +150        | °C   |
| Tstg   | Storage temperature            | -55 to +150 | Ċ    |



### ELECTRICAL CHARACTERISTICS (Ta=25°C)

| Symbol   | Parameter                    | Test conditions                        |     | Limits |     | Unit |
|----------|------------------------------|----------------------------------------|-----|--------|-----|------|
|          | - arameter                   |                                        |     | Тур    | Max | Unit |
| V(BR)CBO | C to B break down voltage    | IC=10 μ A,IE=0                         | 300 |        |     | V    |
| V(BR)EBO | E to B break down voltage    | IE=10 μ A,IC=0                         |     |        | -   | V    |
| V(BR)CEO | C to E break down voltage    | Ic=5mA,RBE=∞,pulse measurement         | 250 |        |     | V    |
| Ісво     | Collector cut off current    | Vc8=150V,IE=0                          |     |        | - 1 | μA   |
| hre *    | DC forward current gain      | VcE=10V,lc=25mA                        | 55  |        | 230 |      |
| VCE(sat) | C to E saturation voltage    | Ic=25mA,IB=2.5mA                       |     |        | 1,5 | V    |
| fr       | Gain band width product      | VCE=10V,IE=-10mA,f=10MHz               | 60  | 80     |     | MHz  |
| Cob      | Collector output capacitance | Vcs=10V,IE=0,f=1MHz,triode measurement |     | 3.5    |     | ρF   |

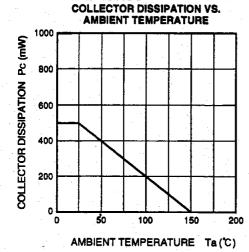
<sup>\* :</sup> It shows her classification in right table

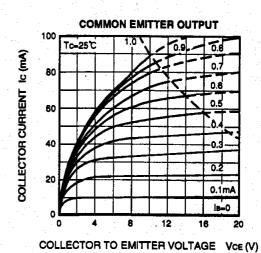
| Marking | SC        | SD        | SE         |
|---------|-----------|-----------|------------|
| hFE     | 55 to 110 | 90 to 180 | 150 to 230 |

## 2SC5210

# FOR SMALL TYPE COLOUR TV CHROMA OUTPUT APPLICATION SILICON NPN TRIPLE DIFFUSED TYPE







2.0
Ta=25C
VcE=10V

1.2

1.2
0.8
0.8
0.4

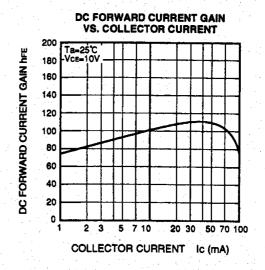
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**COMMON EMITTER INPUT** 

0.6

BASE TO EMITTER VOLTAGE VBE (V)

0.8



**GAIN BAND WIDTH PRODUCT VS. EMITTER CURRENT** fr (MHz) 200 Tc=25°C Vce=10V !=10MHz 180 160 GAIN BAND WIDTH PRODUCT 140 120 100 80 60 40 20 0 -10

EMITTER CURRENT IE (mA)



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